PE4152

Document Category: Product Specification

UltraCMOS® Quad MOSFET Mixer

Peregrine Semiconductor

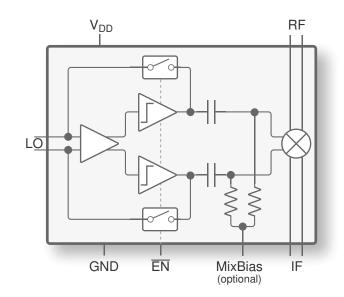
Features

- Quad MOSFET array with integrated LO enable and bypass mode
- · Ultra high linearity in both LO modes
 - LO enable: 25 dBm IIP3, 52 dBm IIP2
 - LO bypass: 24 dBm IIP3, 46 dBm IIP2
- · High isolation in both LO modes
 - LO enable: 30/30 dB LO-RF/IF
 - LO bypass: 60/58 dB LO–RF/IF
- · Low conversion loss in both LO modes
- Packaging 20-lead 4 × 4 × 0.85 mm QFN

Applications

- · Land-mobile-radio (LMR)
 - Portable radio
 - Mobile radio
- · Cellular infrastructure
- Set-top box (STB)/CATV systems

Figure 1 • PE4152 Functional Diagram



Product Description

The PE4152 is a high linearity quad metal-oxide-semiconductor field-effect transistor (MOSFET) mixer with an integrated local oscillator (LO) amplifier. The LO amplifier allows for LO input drive levels of less than 0 dBm to produce third-order intercept point (IIP3) values similar to a quad MOSFET array driven with a 15 dBm LO drive. The PE4152 operates with differential signals at the radio frequency (RF) and intermediate frequency (IF) ports and the integrated LO buffer amplifier drives the mixer core. It can be used as an upconverter or a downconverter.

The PE4152 also offers an integrated LO amplifier bypass option providing additional flexibility for low power or increased linearity operation. The bypassed LO amplifier allows superior LO to RF and LO to IF isolation levels relative to the enabled mode.

The PE4152 is manufactured on Peregrine's UltraCMOS® process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.



Absolute Maximum Ratings

Exceeding absolute maximum ratings listed in **Table 1** may cause permanent damage. Operation should be restricted to the limits in **Table 2**. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

ESD Precautions

When handling this UltraCMOS device, observe the same precautions as with any other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in **Table 1**.

Latch-up Immunity

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.

Table 1 • Absolute Maximum Ratings for PE4152

| Parameter/Condition | Min | Max | Unit | |
|---|-----|------|-------------------|--|
| Supply voltage, V _{DD} | | 4.0 | V | |
| Maximum DC plus peak AC across drain-source | | ±3.3 | V | |
| Maximum DC current across drain-source | | 6 | mA | |
| Maximum AC current across drain-source | | 36 | mA _{P-P} | |
| Storage temperature range | -65 | +150 | °C | |
| Operating junction temperature | | +125 | °C | |
| ESD voltage HBM, all pins ^(*) | | 1000 | V | |
| Note: * Human body model (MIL-STD 883 Method 3015). | | | | |

Recommended Operating Conditions

Table 2 lists the recommended operating conditions for the PE4152. Devices should not be operated outside the recommended operating conditions listed below.

Table 2 • Recommended Operating Conditions for PE4152

| Parameter | Min | Тур | Max | Unit |
|---------------------------------|-----|-----|-----|------|
| Supply voltage, V _{DD} | 2.9 | | 3.1 | V |
| Operating temperature range | -40 | | +85 | °C |
| LO input power (LO enable) | -10 | | -6 | dBm |
| LO input power (LO bypass) | | | 23 | dBm |
| RF input power (LO enable) | | | 2 | dBm |
| RF input power (LO bypass) | | | 2 | dBm |



Electrical Specifications

Table 3 and **Table 4** provide the PE4152 key electrical specifications @ +25 °C, $V_{DD} = 3.0V$, unless otherwise specified.

Table 3 • PE4152 Electrical Specifications—LO Enable Mode

| Parameter | Condition | Min | Тур | Max | Unit |
|-----------------------------------|--|--|------------|--|--|
| LO enable mode | ' | | | | |
| Current drain | A function of frequency | | 9.5 | 16 | mA |
| Off state leakage current | | | | 20 | μΑ |
| RF input frequency | VHF band UHF1 band UHF2 band 700 MHz 800 MHz 900 MHz | 136 380 450 764 851 935 | | 174 470 520 776 870 941 | MHz MHz MHz MHz MHz MHz |
| LO frequency | VHF band UHF1 band UHF2 band 700 MHz 800 MHz 900 MHz | 245.65 270.35 340.35 873.65 741.35 825.35 | | 283.65 360.35 410.35 885.65 760.35 831.35 | MHz MHz MHz MHz MHz MHz |
| IF output frequency | | | 109.65 | | MHz |
| LO input power | | -10 | | -6 | dBm |
| RF input power | | | | 2 | dBm |
| Conversion loss ⁽¹⁾ | VHF, UHF1, UHF2 700, 800 and 900 MHz | | 6.5 7.3 | 7.0 8.25 | dB dB |
| Input IP3 ⁽²⁾ | | 20.5 | 25 | | dBm |
| Input IP2 ⁽³⁾ | VHF, UHF1, UHF2 700, 800 and 900 MHz | 45 40 | 52 50 | | dBm dBm |
| RF to IF isolation ⁽⁴⁾ | VHF, UHF1, UHF2 700, 800 and 900 MHz | 35 35 | 45 45 | | dB dB |
| LO to IF isolation | | 18.5 | 22 | | dB |
| LO to RF isolation | | 26 | 30 | | dB |

Notes:

- 1) Measured with a 1:1 balun on the RF and IF ports.
- 2) Measured with two tones at 2 dBm, 100 kHz spacing.
- 3) Measured with half-IF method.
- 4) Measured with an input frequency equal with IF.



Table 4 • PE4152 Electrical Specifications—LO Bypass Mode

| Parameter | Condition | Min | Тур | Max | Unit |
|-----------------------------------|--|--|------------|--|--|
| LO bypass mode | | | | | |
| Off state leakage current | | | 20 | | μΑ |
| RF input frequency | VHF band UHF1 band UHF2 band 700 MHz 800 MHz 900 MHz | 136 380 450 764 851 935 | | 174 470 520 776 870 941 | MHz MHz MHz MHz MHz MHz |
| LO frequency | VHF band UHF1 band UHF2 band 700 MHz 800 MHz 900 MHz | 245.65 270.35 340.35 873.65 741.35 825.35 | | 283.65 360.35 410.35 885.65 760.35 831.35 | MHz MHz MHz MHz MHz MHz |
| IF output frequency | | | 109.65 | | MHz |
| LO input power | | | | 23 | dBm |
| RF input power | | | | 2 | dBm |
| Conversion loss ⁽¹⁾ | VHF, UHF1, UHF2 700, 800 and 900 MHz | | 6.5 7.5 | 8.0 8.7 | dB dB |
| Input IP3 ⁽²⁾ | VHF, UHF1, UHF2 700, 800 and 900 MHz | 24 19 | 26 24 | | dBm dBm |
| Input IP2 ⁽³⁾ | VHF, UHF1, UHF2 700, 800 and 900 MHz | | 46 46 | | dBm dBm |
| RF to IF isolation ⁽⁴⁾ | VHF, UHF1, UHF2 700, 800 and 900 MHz | | 38 38 | | dB dB |
| LO to IF isolation | | 30 | 58 | | dB |
| LO to RF isolation | | 35 | 60 | | dB |
| Notes: | 1 | I | ı | I | |

Notes:

- 1) Measured with a 1:1 balun on the RF and IF ports.
- 2) Measured with two tones at 2 dBm, 100 kHz spacing.
- 3) Measured with half-IF method.
- 4) Measured with an input frequency equal with IF.



Typical Performance Data

Figure 2-Figure 23 show the typical performance data @ +25 °C, V_{DD} = 3.0V, unless otherwise specified.

Figure 2 • Conversion Loss vs LO Power (LO Enable)

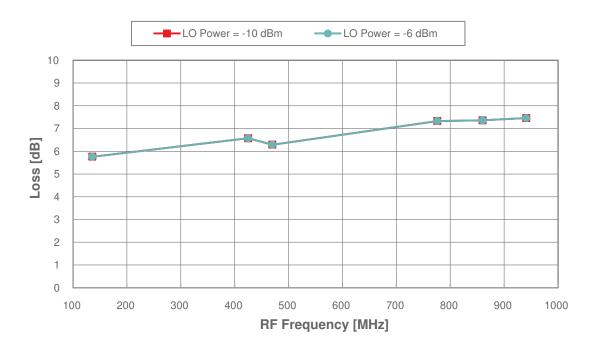


Figure 3 • Conversion Loss vs V_{DD} (LO Enable)

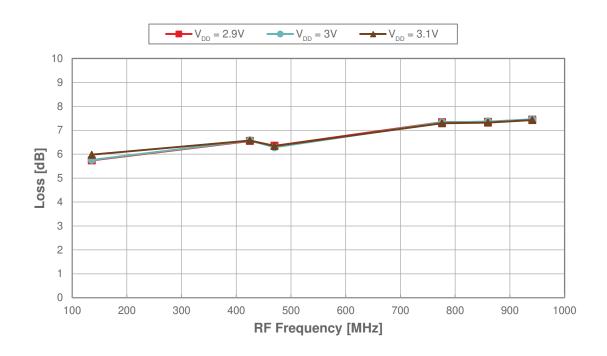




Figure 4 • Conversion Loss vs Temperature (LO Enable)

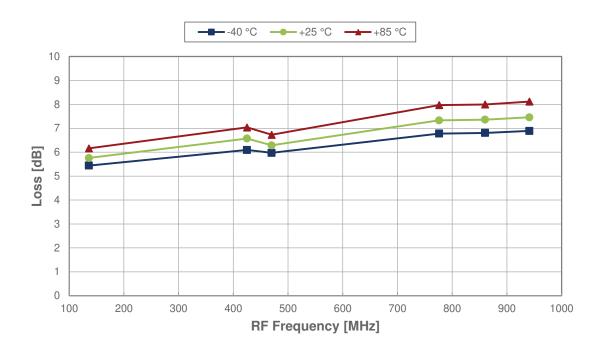


Figure 5 • Conversion Loss vs LO Power (LO Bypass Enable)

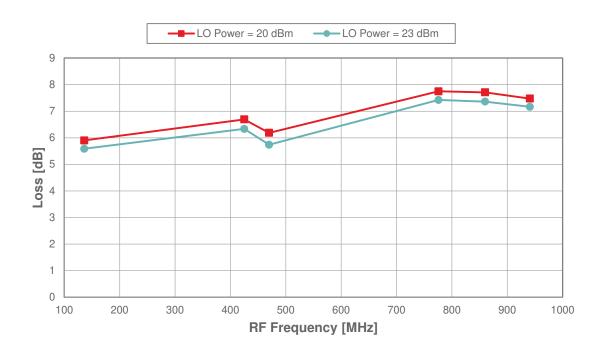




Figure 6 • Conversion Loss vs V_{DD} (LO Bypass Enable)

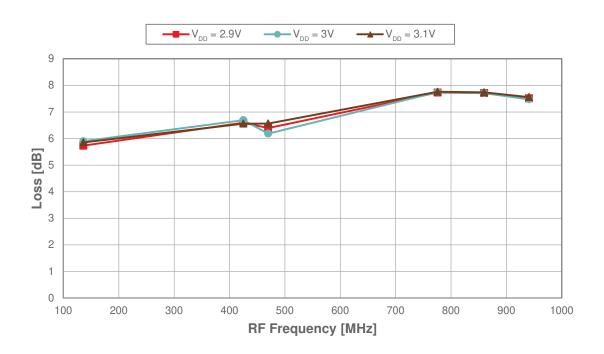


Figure 7 • Conversion Loss vs Temperature (LO Bypass Enable)

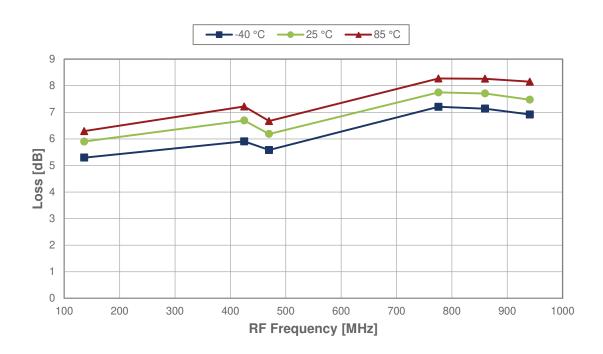




Figure 8 • IIP2 / IIP3 vs LO Power (LO Bypass)

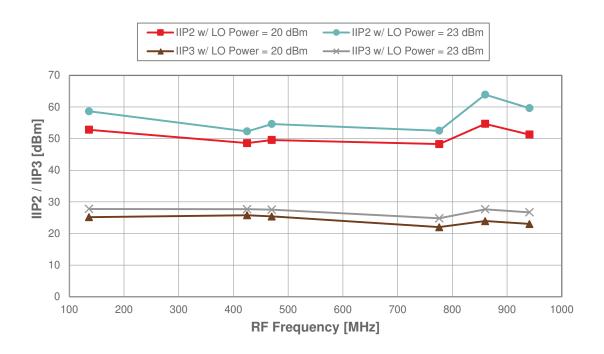


Figure 9 • IIP2 / IIP3 vs Temperature (LO Bypass)

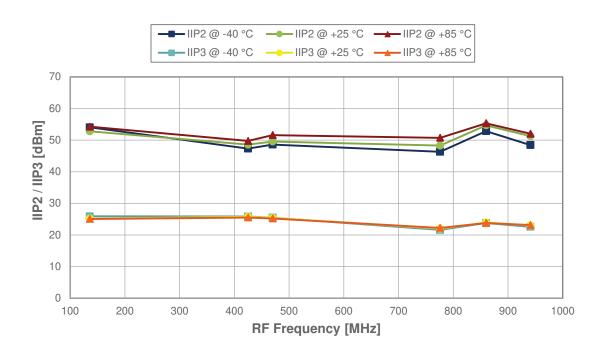




Figure 10 • IIP2 / IIP3 vs LO Power (LO Enable)

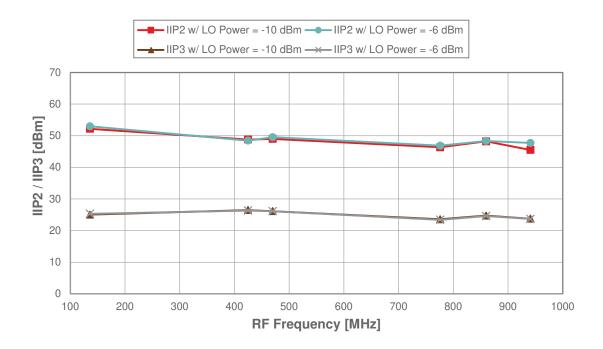


Figure 11 • IIP2 / IIP3 vs Temperature (LO Enable)

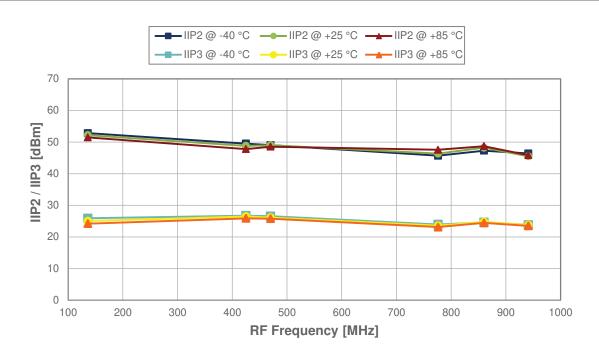




Figure 12 • LO-IF Isolation vs LO Power (LO Bypass)

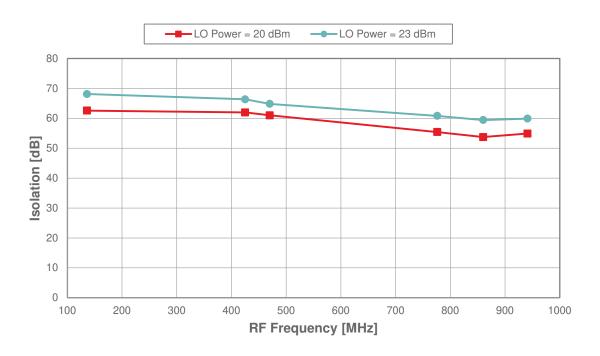


Figure 13 • LO-IF Isolation vs Temperature (LO Bypass)

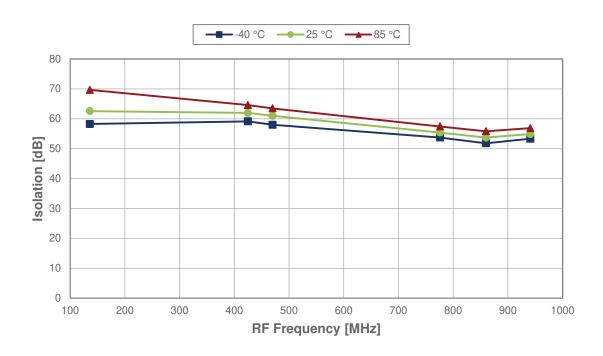




Figure 14 • LO-IF Isolation vs LO Power (LO Enable)

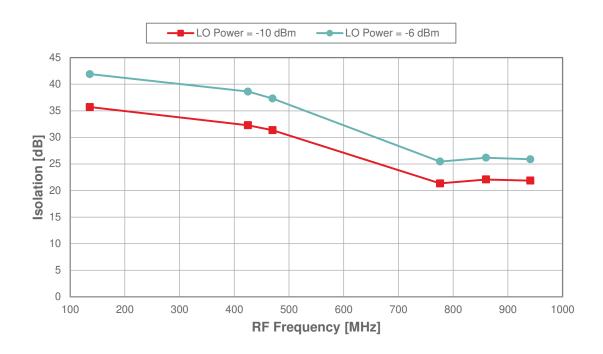


Figure 15 • LO-IF Isolation vs Temperature (LO Enable)

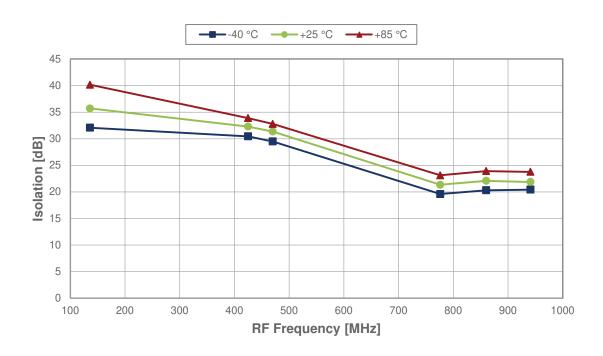




Figure 16 • LO-RF Isolation vs LO Power (LO Bypass)

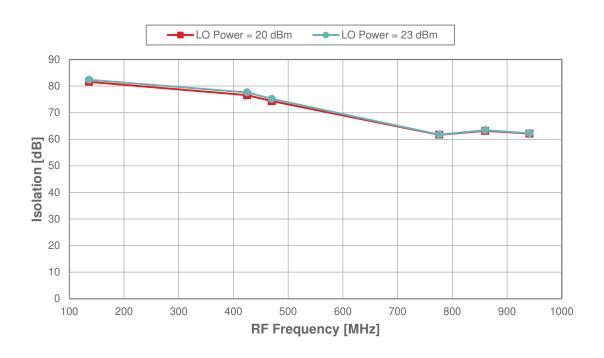


Figure 17 • LO-RF Isolation vs Temperature (LO Bypass)

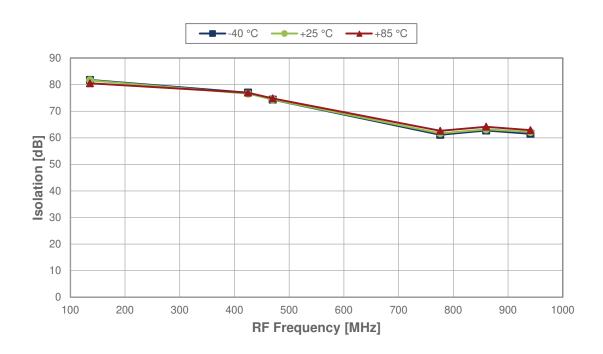




Figure 18 • LO-RF Isolation vs LO Power (LO Enable)

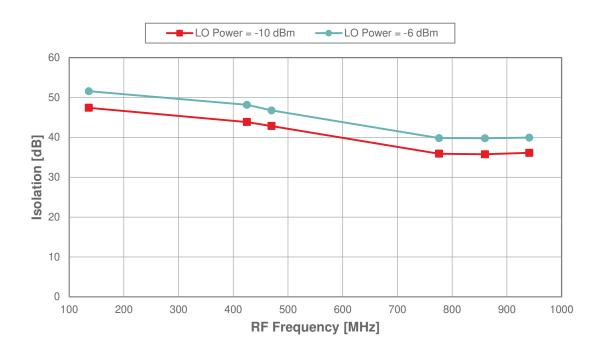


Figure 19 • LO-RF Isolation vs Temperature (LO Enable)

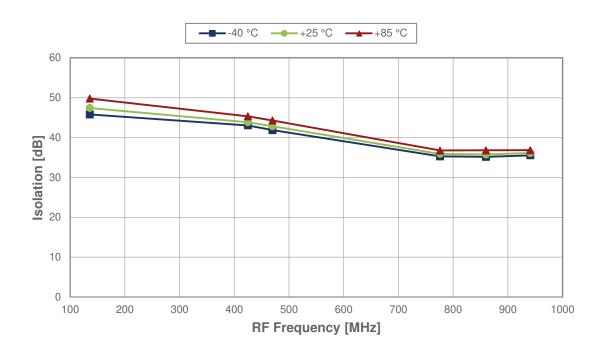




Figure 20 • RF-IF Isolation vs LO Power (LO Bypass)

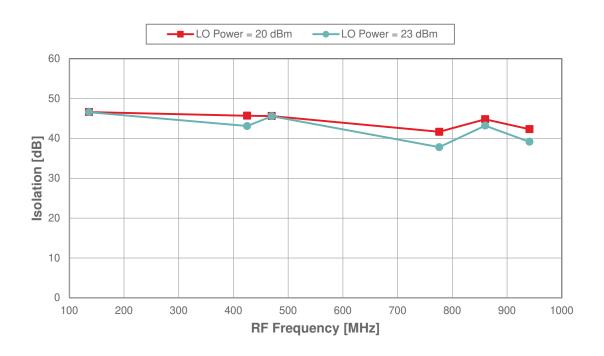


Figure 21 • RF—IF Isolation vs Temperature (LO Bypass)

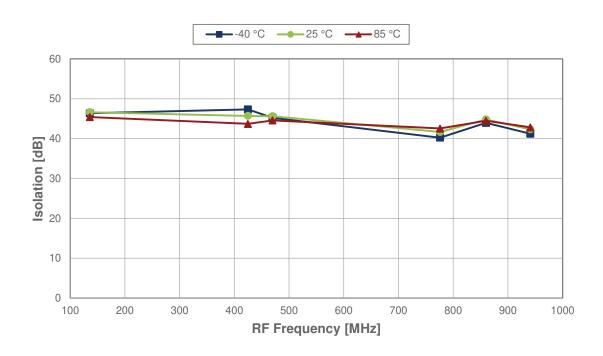




Figure 22 • RF-IF Isolation vs LO Power (LO Enable)

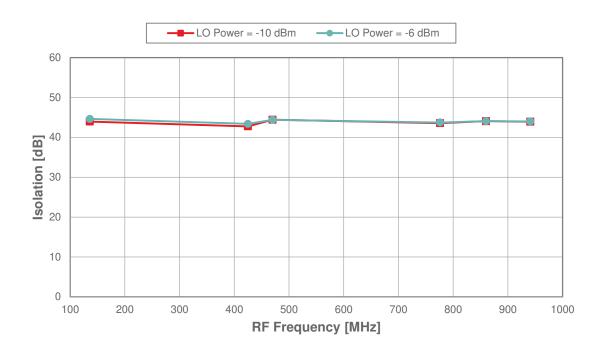
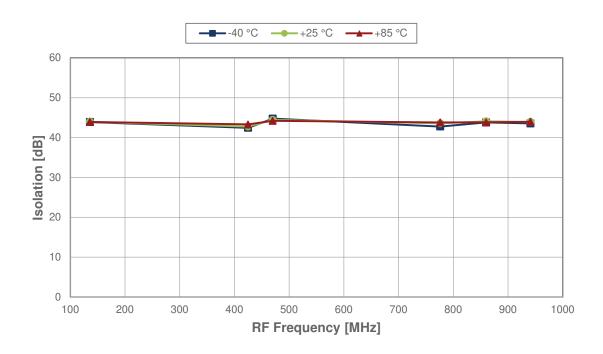


Figure 23 • RF–IF Isolation vs Temperature (LO Enable)





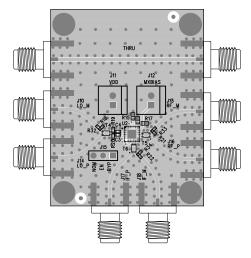
Evaluation Kit

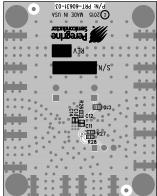
The PE4152 evaluation board (EVB) was designed to ease customer evaluation of the PE4152 mixer. The EVB is assembled with a PE4152 field-effect transistor (FET) mixer, baluns, headers and SubMiniature version A (SMA) connectors.

V_{DD} is applied to the device at J11. The LO bypass mode is selected by applying an active high signal to pin 6 via jumper J15 as show in **Figure 24**. The baluns have been selected to provide uniform amplitude and phase balance across the 100 to 1000 MHz frequency range.

The PCB design should use proper RF layout techniques for best performance. The signal lines should have 50Ω impedence and the package ground (exposed paddle) should be connected directly to the ground plane.

Figure 24 • Evaluation Kit Layout for PE4152







Pin Information

This section provides pinout information for the PE4152. **Figure 25** shows the pin map of this device for the available package. **Table 5** provides a description for each pin.

Figure 25 • Pin Configuration (Top View)

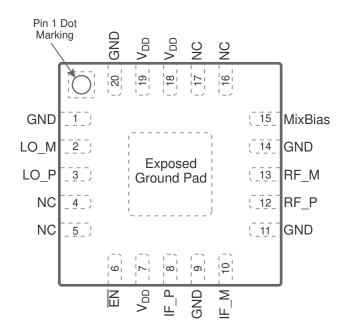


Table 5 • Pin Descriptions for PE4152

| Pin No. | Pin Name | Description |
|---------------------|------------------------|--|
| 1, 9, 11, 14, 20 | GND | Ground |
| 2 | LO_M | Minus LO output |
| 3 | LO_P | Positive LO output |
| 4, 5, 16, 17 | NC | No connect |
| 6 | EN | LO enable (active low) |
| 7, 18, 19 | V _{DD} | Supply voltage |
| 8 | IF_P | Positive IF port |
| 10 | IF_M | Minus IF port |
| 12 | RF_P | Positive RF input |
| 13 | RF_M | Minus RF port |
| 15 | MixBias ^(*) | External mixer bias |
| Pad | GND | Exposed pad: ground for proper operation |

Note: * For applications where the DC level of the RF and IF ports are not at 0V, the MixBias pin can be set to the equivalent DC bias level. For example, if the RF and IF signals are biased at 1 VDC, a 1V level can be applied to the MixBias pin. This will maintain the RF performance similar to the 0V case. The MixBias pin can be used in both LO states.



Packaging Information

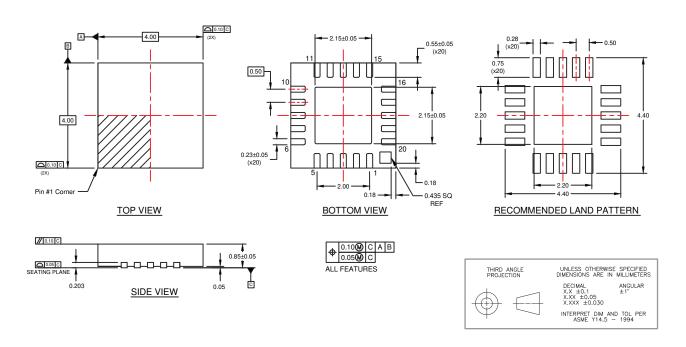
This section provides packaging data including the moisture sensitivity level, package drawing, package marking information and tape-and-reel information.

Moisture Sensitivity Level

The moisture sensitivity level rating for the PE4152 in the 20-lead 4 × 4 × 0.85 mm QFN package is MSL1.

Package Drawing

Figure 26 • Package Mechanical Drawing for 20-lead 4 × 4 × 0.85 mm QFN



Top-Marking Specification

Figure 27 • Package Marking Specifications for PE4152



= Pin 1 indicator

YY = Last two digits of assembly year

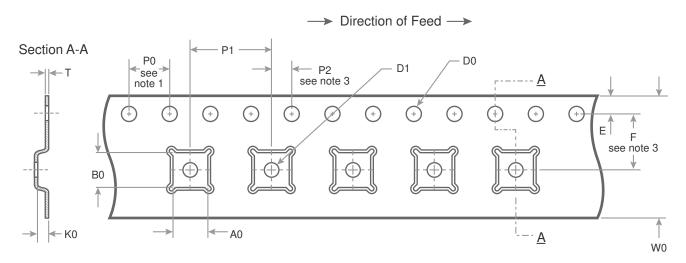
WW = Assembly work week

ZZZZZZ = Assembly lot code (maximum six characters)



Tape and Reel Specification

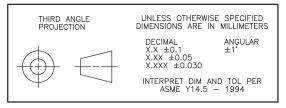
Figure 28 • Tape and Reel Specifications for 20-lead $4 \times 4 \times 0.85$ mm QFN

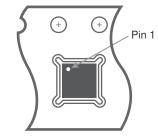


Notes:

| A0 | 3.30 |
|----|------------------|
| B0 | 3.30 |
| K0 | 1.10 |
| D0 | 1.50 + 0.1/ -0.0 |
| D1 | 1.5 min |
| E | 1.75 ± 0.10 |
| F | 5.50 ± 0.05 |
| P0 | 4.00 |
| P1 | 8.00 |
| P2 | 2.00 ± 0.05 |
| Т | 0.30 ± 0.05 |
| W0 | 12.00 ± 0.3 |

- 1. 10 Sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber in compliance with EIA 481
- 3. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole





Device Orientation in Tape



Ordering Information

Table 6 lists the available ordering codes for the PE4152 as well as available shipping methods.

Table 6 • Order Codes for PE4152

| Order Codes | Description | Packaging | Shipping Method |
|-------------|---------------------------------|----------------------------|------------------|
| PE4152A-Z | PE4152 mixer with integrated LO | Green 20-lead 4 × 4 mm QFN | 3000 units / T&R |
| EK4152-02 | PE4152 Evaluation kit | Evaluation kit | 1 / Box |

Document Categories

Advance Information

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

Preliminary Specification

The datasheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

Product Specification

The datasheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

Sales Contact

For additional information, contact Sales at sales@psemi.com.

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Product Brief

This document contains a shortened version of the datasheet. For the full datasheet, contact sales@psemi.com.

Not Recommended for New Designs (NRND)

This product is in production but is not recommended for new designs.

End of Life (EOL)

This product is currently going through the EOL process. It has a specific last-time buy date.

Obsolete

This product is discontinued. Orders are no longer accepted for this product.